

N-Channel 100-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{(BR)DSS} (V)	$r_{DS(on)}(\Omega)$			
100	0.040 at V _{GS} = 10 V	55 ^a		

FEATURES

- DT-Trench Power MOSFET
- 175 °C Junction Temperature
- Low Thermal Resistance Package
- 100 % R_g and UIS Tested

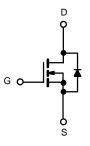


APPLICATIONS

• Isolated DC/DC Converters



D²PAK



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	T _C = 25 °C, unless oth	erwise noted		
Parameter	-	Symbol	Limit	Unit
Drain-Source Voltage		V _{DS}	100	V
Gate-Source Voltage		V _{GS}	± 20	
Continuous Drain Current (T _J = 175 °C)	T _C = 25 °C	1-	55 ^a	
	T _C = 125 °C	I _D	30 ^a	A
Pulsed Drain Current		I _{DM}	165	7
Avalanche Current	L = 0.1 mH	I _{AS}	30	
Single Pulse Avalanche Energy ^b	L = 0.111111	E _{AS}	50	mJ
b	T _C = 25 °C	D.	350 ^c	W
Maximum Power Dissipation ^b	T _A = 25 °C ^d	$ P_{D}$ $-$	3.50	VV
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 175	°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Limit	Unit	
Junction-to-Ambient	PCB Mount (TO-263) ^d	R _{thJA}	45	°C/W	
Junction-to-Case (Drain)		R _{thJC}	0.45	C/VV	

Notes:

- a. Package limited.
- b. Duty cycle \leq 1 %.
- c. See SOA curve for voltage derating.
- d. When Mounted on 1" square PCB (FR-4 material).



Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{DS} = 0 \text{ V}, I_{D} = 250 \mu\text{A}$	100			٧	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1		4	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
		$V_{DS} = 80 \text{ V}$, $V_{GS} = 0 \text{ V}$			1	μΑ	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 80 V, V _{GS} = 0 V, T _J = 125 °C			50		
		V _{DS} = 80 V , V _{GS} = 0 V, T _J = 175 °C			250		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	50			Α	
		V _{GS} = 10 V, I _D = 20 A		0.040	0.055	Ω	
Drain-Source On-State Resistance ^a	r _{DS(on)}	V _{GS} = 10 V, I _D = 15 A, T _J = 125 °C		0.065	0.080		
		V _{GS} = 10 V, I _D = 10 A, T _J = 175 °C		0.085	0.120		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 80 V, I _D = 20 A		110		S	
Dynamic ^b							
Input Capacitance	C _{iss}			4980		pF	
Output Capacitance	C _{oss}	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$		380			
Reverse Transfer Capacitance	C _{rss}	1		210		1	
Total Gate Charge ^c	Qg			93			
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = 80 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$		21		nC	
Gate-Drain Charge ^c	Q _{gd}			37		1	
Gate Resistance	R _g			1.8		Ω	
Turn-On Delay Time ^c	t _{d(on)}			24	35		
Rise Time ^c	t _r	$V_{DD} = 80 \text{ V}, R_{L} = 1.5 \Omega$		220	330		
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong 20 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 2.5 \Omega$		45	70	ns	
Fall Time ^c	t _f			200	300	1	
Source-Drain Diode Ratings and Cha	aracteristics 7	T _C = 25 °C ^b					
Continuous Current	I _S				55	۸	
Pulsed Current	I _{SM}				165	Α	
Forward Voltage ^a	V _{SD}	I _F = 20 A, V _{GS} = 0 V		1.0	1.5	V	
Reverse Recovery Time	t _{rr}			110	180	ns	
Peak Reverse Recovery Current	I _{RM(REC)}	I _F = 20 A, di/dt = 100 A/μs		7	11	Α	
Reverse Recovery Charge	Q _{rr}			0.49	1.0	μС	

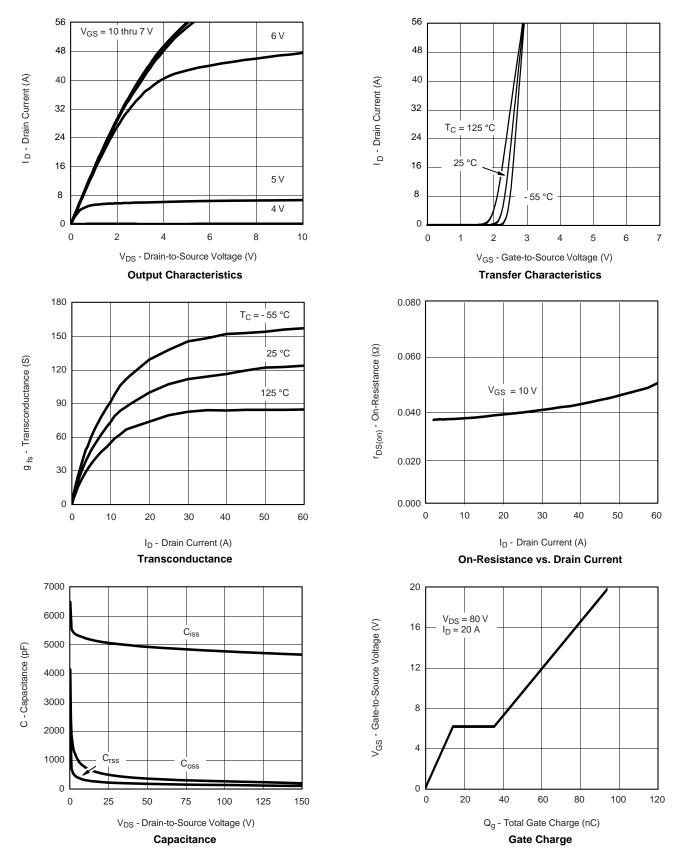
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

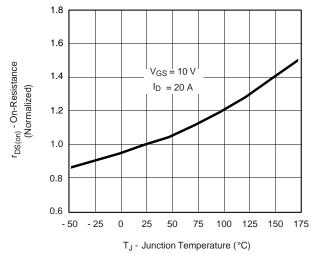


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

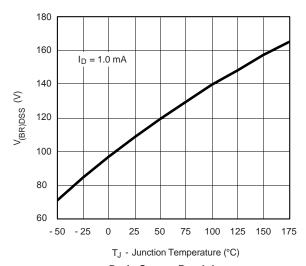




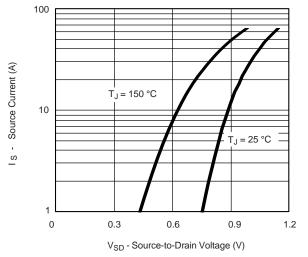
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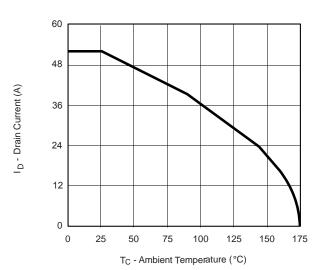
On-Resistance vs. Junction Temperature



Drain Source Breakdown vs. Junction Temperature



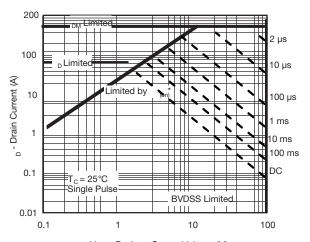
Source-Drain Diode Forward Voltage



Maximum Avalanche and Drain Current vs. Case Temperature

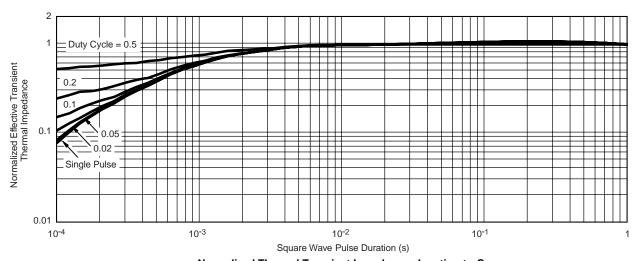


THERMAL RATINGS



 $\label{eq:VDS} $$V_{DS}$ - Drain-to-SourceVoltage (V) $$^*V_{GS} > minimum\,V_{GS}$ at which $r_{DS(on)}$ is specified$

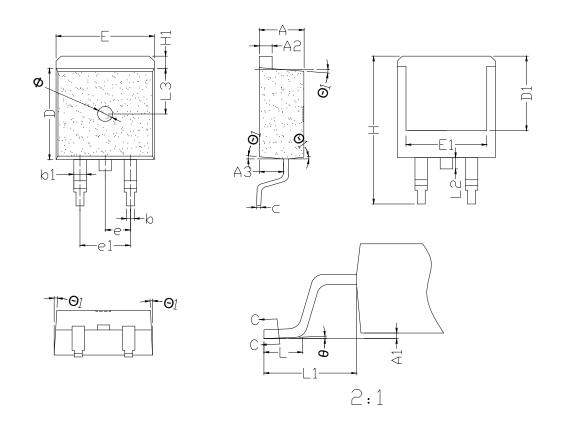
Safe Operating Area



 ${\bf Normalized\ Thermal\ Transient\ Impedance,\ Junction-to-Case}$

DTK9830 www.din-tek.jp

TO-263 PACKAGE OUTLINE



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	TYP	MAX	SYMBOL	MIN	TYP	MAX
Α	4.10	4.50	4.80	е	2.35	2.54	2.75
A1	0.00	0.10	0.30	e1	5.08REF		
A2	1.10	1.30	1.50	Н	14.50	15.15	16.00
A3	2.15	2.50	3.10	H1	1.00	1.28	1.75
b	0.60	0.80	1.05	L	1.80	2.23	2.90
b1	1.05	1.33	1.50	L1	4.30	4.75	5.50
С	0.33	0.50	0.66	L2	1.00	1.30	1.85
D	8.40	9.20	9.60	L3	0.90	4.65	9.00
D1	7.50REF		ф	0°	2°	5°	
E	9.60	10.02	10.80	φ1	2°	-	7°
E1	7.60	9.88	10.30	Φ		1.5BSC	





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